



SI8487DB-T1-E1 Information



For Reference Only

Part Number SI8487DB-T1-E1 **Manufacturer** Vishay Siliconix

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET P-CH 30V MICROFOOT

Package 4-UFBGA

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









SI8487DB-T1-E1 Specifications

Manufacturer Part Number	SI8487DB-T1-E1
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	4-UFBGA
Series	TrenchFET?
FET Type	P-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	-
Drive Voltage (Max Rds On, Min Rds On)	2.5V, 10V
Vgs(th) (Max) @ Id	1.2V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	80nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	2240pF @ 15V
Vgs (Max)	±12V
FET Feature	-
Power Dissipation (Max)	1.1W (Ta), 2.7W (Tc)
Rds On (Max) @ Id, Vgs	31 mOhm @ 2A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	4-Microfoot
Package / Case	4-UFBGA
	Report errors?

SI8487DB-T1-E1 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

SI8487DB-T1-E1 Payment Methods



















SI8487DB-T1-E1 Shipping Methods













If you have any question about SI8487DB-T1-E1, please do not hesitate to contact us!

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